NSSHNBO

RP503x SERIES

600mA^{*} Step-down DC/DC Converter with Synchronous Rectifier

NO.EA-235-140530

OUTLINE

The RP503x Series are low supply current CMOS-based 600mA^{*} step-down DC/DC Converters with synchronous rectifier. Each of these ICs consists of an oscillator, a switching control circuit, a reference voltage unit, an error amplifier, a soft-start circuit, UVLO circuit, a latch protection circuit, switching transistors, and so on. A low ripple, high efficiency step-down DC/DC converter can be easily composed of this IC with only an inductor and capacitors.

In terms of the output voltage, since the feedback resistances are built-in, the voltage is fixed internally. 0.1V step output can be set by laser-trim and 1.5% or 18mV tolerance depending on the output voltage is guaranteed. RP503x is PWM/VFM auto switching control in which mode automatically switches from PWM mode to high-efficiency VFM mode in low output current. The efficiency in low output current (VFM mode) improved compared with existing products.

As protection circuits, the current limit circuit which limits peak current of Lx at each clock cycle, and the latch type protection circuit which works if the term of the over-current condition keeps on a certain time exist. The latch-type protection circuit works to latch an internal driver with keeping it disable. To release the condition of the protection, after disabling this IC with a chip enable circuit, enable it again, or restart this IC with power-on or make the supply voltage at UVLO detector threshold level or lower than UVLO.

Since packages are WLCSP-6-P2, DFN1616-6, SOT-23-5, high density mounting on boards is possible.

*)This is an approximate value, because output current depends on conditions and external parts.

FEATURES

- Supply CurrentTyp. 20μA (at VFM mode, at no load)
- Standby CurrentMax. 5µA
- Input Voltage Range2.5V to 5.5V (Absolute maximum rating; 6.5V)
- Output Voltage Range.....0.8V to 2.5V (0.1V step)
- Output Voltage Accuracy......±1.5% (Vouτ≥1.2V), ±18mV (Vouτ<1.2V)
- Temperature-Drift Coefficient of Output Voltage ... Typ. ±100ppm/°C
- Oscillator FrequencyTyp. 2.0MHz
- Oscillator Maximum Duty CycleMin. 100%
- Built-in Driver ON ResistanceTyp. Pch. 0.34Ω , Nch. 0.43Ω (V_{IN}=3.6V)
- UVLO Detector Threshold.....Typ. 2.2V
- Soft Start Time.....Typ. 0.15ms
- Lx Current Limit......Typ. 800mA
- Latch type Protection CircuitTyp. 1.5ms
- Two choices of Switching Mode.....Automatic PWM/VFM mode change
- PackagesDFN1616-6, WLCSP-6-P2, SOT-23-5

APPLICATIONS

- Power source for battery-powered equipment.
- Power source for hand-held communication equipment, cameras, VCRs, camcorders.
- Power source for HDD, portable equipment.

BLOCK DIAGRAMS



RP503Zxx1A RP503Lxx1A

RP503Zxx2A RP503Lxx2A



* RP503Z (WLCSP-6-P2) is the discontinued product. As of June in 2016.

RP503x



RP503Nxx2A



SELECTION GUIDE

The output voltage, auto discharge function, and package for the ICs can be selected at the user's request.

Product Name	Package	Quantity per Reel	Pb Free	Halogen Free	
RP503Zxx*A-E2-F	WLCSP-6-P2	5,000 pcs	Yes	Yes	
RP503Lxx*A-TR	DFN1616-6	5,000 pcs	Yes	Yes	
RP503Nxx*A-TR-FE	SOT-23-5	3,000 pcs	Yes	Yes	
xx: The output voltage can be designated in the range from 0.8V(08) to 2.5V(25) in 0.1V steps [*] . (For other voltages, please refer to MARK INFORMATIONS.)					

* : The auto discharge function at off state are options as follows.

(1) without auto discharge function at off state

(2) with auto discharge function at off state

*) 0.05V step is also available as a custom code.

PIN CONFIGURATIONS













PIN DESCRIPTIONS

• WLCSP-6-P2

Pin No	Symbol	Pin Description	
1	Vout	Output Pin	
2	PGND	Ground Pin	
3	Lx	Lx Switching Pin	
4	Vin	Input Pin	
5	AGND	Ground Pin	
6	CE	Chip Enable Pin ("H" Active)	

• DFN1616-6

Pin No	Symbol	Pin Description	
1	CE	Chip Enable Pin ("H" Active)	
2	AGND	Ground Pin	
3	VIN	Input Pin	
4	Lx	Lx Switching Pin	
5	PGND	Ground Pin	
6	Vout	Output Pin	

*) Tab is GND level. (They are connected to the reverse side of this IC.)

The tab is better to be connected to the GND, but leaving it open is also acceptable.

• SOT-23-5

Pin No	Symbol	Pin Description	
1	Vout	Output Pin	
2	GND	Ground Pin	
3	Lx	Lx Switching Pin	
4	VIN	Input Pin	
5	CE	Chip Enable Pin ("H" Active)	

ABSOLUTE MAXIMUM RATINGS

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AGND=PGND=0V
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Symbol	Item	Rating	Unit
Vin	Input Voltage	-0.3 to 6.5	V
VLx	Lx pin Voltage	–0.3 to V _{IN} +0.3	V
Vce	CE Pin Input Voltage	-0.3 to 6.5	V
Vout	Output Voltage	-0.3 to 6.5	V
ILx	Lx Pin Output Current	800	mA
	Power Dissipation (WLCSP-6-P2) *	650	
PD	Power Dissipation (DFN1616-6) *	640	mW
	Power Dissipation (SOT-23-5) *	420	
Topt	Operating Temperature Range	-40 to 85	°C
Tstg	Storage Temperature Range	-55 to 125	°C

*) For Power Dissipation, please refer to PACKAGE INFORMATION.

ABSOLUTE MAXIMUM RATINGS

Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause the permanent damages and may degrade the life time and safety for both device and system using the device in the field. The functional operation at or over these absolute maximum ratings is not assured.

ELECTRICAL CHARACTERISTICS

• RP503x

Topt=25°C

Symbol	Item Conditions		Min.	Тур.	Max.	Unit	
Vin	Operating Input Voltage			2.5		5.5	V
Vout	Output Voltage	VIN=VCE=3.6V	$V_{\text{OUT}} \geq 1.2V$	×0.985		×1.015	V
V 001	Oulput Voltage	VIN=VCE=3.0V	Vout < 1.2V	-18		18	mV
ΔV out/ ΔT opt	Output Voltage Temperature Coefficient	$-40^{\circ}C \le T_{opt} \le 83$	5°C		±100		ppm ∕°C
fosc	Oscillator Frequency	VIN=VCE=VOUT+1.7	7V	1.7	2.0	2.3	MHz
DD	Supply Current	VIN=VCE=5.5V, VC	рит= 5.5 V		20	32	μA
Istandby	Standby Current	VIN=5.5V, VCE=0	/		0	5	μA
Ronp	ON Resistance of Pch Tr.	VIN=3.6V, ILX=-10	00mA		0.34		Ω
Ronn	ON Resistance of Nch Tr.	VIN=3.6V, ILX=-10)0mA		0.43		Ω
LXleakH	Lx Leakage Current "H"	VIN=VLX=5.5V, VC	e=0V	-1	0	5	μA
LXleakL	Lx Leakage Current "L"	VIN=5.5V, VCE=VLX=0V		-5	0	1	μA
Ілоптн	Vout "H" Input Current	VIN=VOUT=5.5V, VCE=0V		-1	0	1	μA
IVOUTL	Vout "L" Input Current	VIN=5.5V, VCE=VOUT=0V		-1	0	1	μA
Ісен	CE "H" Input Current	VIN=VCE=5.5V		-1	0	1	μA
ICEL	CE "L" Input Current	VIN=5.5V, VCE=0V		-1	0	1	μA
VCEH	CE Input Voltage "H"	VIN=5.5V		1.0			V
Vcel	CE Input Voltage "L"	Vin=2.5V				0.4	V
Maxduty	Oscillator Maximum Duty Cycle			100			%
t start	Soft-start Time*	VIN=VCE=3.6V			150	300	μS
LXlim	Lx Current Limit	VIN=VCE=3.6V		600	800		mA
tprot	Protection Delay Time	VIN=VCE=3.6V		0.5	1.5	5.0	ms
VUVLO1	UVLO Detector Threshold	VIN=VCE		2.1	2.2	2.3	V
VUVLO2	UVLO Released Voltage	VIN=VCE		2.2	2.3	2.4	V
RLOW	Low Output Nch Tr. ON Resistance (RP503xxx2A only)	VIN=3.6V, VCE=0V			30		Ω

Test circuit is "OPEN LOOP" and AGND=PGND=0V unless otherwise noted. *) The time until the 90% voltage of setting voltage.

RECOMMENDED OPERATING CONDITIONS (ELECTRICAL CHARACTERISTICS)

All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if when they are used over such conditions by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.

TEST CIRCUITS



* RP503Z (WLCSP-6-P2) is the discontinued product. As of June in 2016.

RP503x



Pch • Nch transistor ON resistance / Output Delay for Protection / Lx Current limit





UVLO Detector Threshold • Released Voltage

TYPICAL APPLICATION



RP503L/ZxxxA



RP503NxxxA

Symbol	Parts Recommendation		
CIN	4.7μF	Ceramic	C1608JB0J475K (TDK)
Соит	10µF	Ceramic	C1608JB0J106M (TDK)
L	4.7μΗ	SMD inductor	NR 3010T 4R7M (TAIYO YUDEN)

• If V_{IN} is in the range of 3.0V to 4.5V and V_{OUT} is 1.2V, the following small-sized components can be used.

Symbol			
	2.2µH	SMD inductor	CPL2510T2R2M (TDK)
L	4.7μΗ	SMD inductor	BRFL2518T4R7M (TAIYO YUDEN)
	2.2µH	Multilayer chip inductor	MIPS2520D2R2 (FDK)
CIN	2.2μF×2	Ceramic	GRM155B30J225M (Murata)

• If V_{IN} is in the range of 3.0V to 4.5V, V_{OUT} is 1.2V, and I_{OUT} is lower than 500mA, the following small and Iow-profile components can be used.

Symbol			
CIN	4.7μF	Ceramic	GRM185B30J475ME15 (Murata)
Соит	10µF	Ceramic	GRM155R60G106ME44 (Murata)
L	2.2µH	SMD inductor	CPL2006T2R2M (TDK)

TECHNICAL NOTES

When using these ICs, consider the following points:

- · Set the same level as AGND and PGND.
- Set external components such as an inductor, C_{IN}, C_{OUT} as close as possible to the IC, in particular, minimize the wiring to V_{IN} pin and PGND pin. Reinforce the V_{IN}, PGND, and V_{OUT} lines sufficiently. Large switching current may flow in these lines. If the impedance of V_{IN} and PGND lines is too large, the internal voltage level in this IC may shift caused by the switching current, and the operation might be unstable. The wiring between V_{OUT} and load and between L and V_{OUT} should be separated.
- Use external ceramic capacitors with good frequency characteristics and ESR. C_{IN} between V_{IN} and GND with a capacity of 4.7μF or more and C_{OUT} with a capacity of 10μF or more are recommended.
- Choose an inductor with inductance range from 2.2μH to 4.7μH. The phase compensation has been made by these values with output capacitors. The recommendation characteristics of the inductor are low DC resistance, large enough permissible current, and strong against the magnetic saturation. Inductance value may shift depending on an inductor. If the inductance value at an actual load current is low, Lx peak current may increase and may overlap the Lx current limit. As a result, over current protection may work.
- · Over current protection circuit may be affected by self-heating and heat radiation environment.
- *The performance of power source circuits using these ICs extremely depends upon the peripheral circuits. Pay attention in the selection of the peripheral circuits. In particular, design the peripheral circuits in a way that the values such as voltage, current, and power of each component, PCB patterns and the IC do not exceed their respected rated values. (such as the voltage, current, and power)

Operation of step-down DC/DC converter and Output Current

The DC/DC converter charges energy in the inductor when Lx transistor is ON, and discharges the energy from the inductor when Lx transistor is OFF and controls with less energy loss, so that a lower output voltage than the input voltage is obtained. The operation will be explained with reference to the following diagrams:

<Basic Circuit>





- Step 1: Pch Tr. turns on and current IL (=i1) flows, and energy is charged into CL. At this moment, IL increases from ILmin (=0) to reach ILmax in proportion to the on-time period (ton) of Pch Tr.
- Step 2: When Pch Tr. turns off, Synchronous rectifier Nch Tr. turns on in order that L maintains IL at ILmax, and current IL (=i2) flows.
- Step 3: IL (=i2) decreases gradually and reaches IL=ILmin=0 after a time period of topen, and Nch Tr. turns off. Provided that in the continuous mode, next cycle starts before IL becomes to 0 because toff time is not enough. In this case, IL value increases from this ILmin (>0).

In the case of PWM control system, the output voltage is maintained by controlling the on-time period (ton), with the oscillator frequency (fosc) being maintained constant.

The maximum value (ILmax) and the minimum value (ILmin) of the current flowing through the inductor are the same as those when Pch Tr. turns on and off.

The difference between ILmax and ILmin, which is represented by ΔI :

 $\Delta I = ILmax - ILmin = Vout \times topen / L = (V_{IN} - V_{OUT}) \times ton / L \quadEquation 1$

wherein,

 $\begin{array}{l} T=1 \ / \ fosc=ton+toff \\ duty \ (\%)=ton \ / \ T\times 100=ton\times fosc\times 100 \\ topen\leq toff \end{array}$

In Equation 1, $V_{OUT} \times t_{open} / L$ and $(V_{IN} - V_{OUT}) \times t_{on} / L$ respectively show the change of the current at "ON", and the change of the current at "OFF".

Discontinuous mode and Continuous mode

When the output current (IouT) is relatively small, topen < toff as illustrated in the above diagram. In this case, the energy is charged in the inductor during the time period of ton and is discharged in its entirely during the time period of toff, therefore ILmin becomes to zero (ILmin=0). When IouT is gradually increased, eventually, topen becomes to toff (topen=toff), and when IouT is further increased, ILmin becomes larger than zero (ILmin>0). The former mode is referred to as the discontinuous mode and the latter mode is referred to as continuous mode.



In the continuous mode, when Equation 1 is solved for ton and assumed that the solution is tonc,

When ton<tonc, the mode is the discontinuous mode, and when ton=tonc, the mode is the continuous mode.

Output Current and selection of External components

The relation between the output current and external components is as follows:

(Wherein, Ripple Current p-p value is described as I_{RP}, ON resistance of Pch Tr. and Nch Tr. of Lx are respectively described as R_{ONP} and R_{ONN}, and the DC resistor of the inductor is described as R_L.) When Pch Tr. of Lx is ON:

When Pch Tr. of Lx is "OFF" (Nch Tr. is "ON"):

 $L \times I_{RP} \ / \ toff = R_{ONN} \times I_{OUT} + V_{OUT} + R_L \times I_{OUT} \ Equation \ 4$

Put Equation 4 to Equation 3 and solve for ON duty of Pch transistor, Don = ton / (toff + ton),

 $D_{ON} = (V_{OUT} + R_{ONN} \times I_{OUT} + R_{L} \times I_{OUT}) / (V_{IN} + R_{ONN} \times I_{OUT} - R_{ONP} \times I_{OUT})....Equation 5$

Ripple Current is as follows:

 $I_{\text{RP}} = (V_{\text{IN}} - V_{\text{OUT}} - R_{\text{ONP}} \times I_{\text{OUT}} - R_{\text{L}} \times I_{\text{OUT}}) \times D_{\text{ON}} / \text{ fosc } / L....Equation 6$

wherein, peak current that flows through L, and Lx Tr. is as follows:

ILxmax = Iout + IRP / 2Equation 7

*Consider ILxmax, condition of input and output and select external components.

*The above explanation is directed to the calculation in an ideal case in continuous mode.

TIMING CHART

(1) Soft Start Time

• In the case of starting this IC with CE

In the case of starting this IC with CE, the operation can be as in the timing chart below.

When the voltage of CE pin (V_{CE}) is beyond the threshold level, the operation of the IC starts. The threshold voltage of CE pin is in between CE "H" input voltage (V_{CEH}) and CE "L" input voltage (V_{CEL}) described in the electrical characteristics table. Soft-start circuit operates, and after the certain time, the reference voltage inside the IC (V_{REF}) is rising gradually up to the constant value.



Soft-start time is the time interval from soft start circuit starting point to the reference voltage level reaching point up to this constant level.

*Soft start time is not always equal to the turn-on speed of DC/DC converter. The power supply capacity for this IC, load current, inductance and capacitance values affect the turn-on speed.

• In the case of starting with power supply

In the case of starting with power supply, when the input voltage (V_{IN}) is larger than UVLO released voltage (V_{UVLO2}), soft start circuit operates, and after that, the same explanation above is applied to the operation. Soft-start time is the time interval from soft start circuit starting point to the reference voltage level reaching point up to this constant level.



*Turn-on speed is affected by next conditions;

(a) Input Voltage (V_{IN}) rising speed depending on the power supplier to the IC and input capacitor C_{IN} .

(b) Output Capacitor C_{OUT} value and load current value.

(2) Under Voltage Lockout (UVLO) Circuit

The step-down DC/DC converter stops and ON duty becomes 100%, if input voltage (V_{IN}) becomes less than the set output voltage (Set V_{OUT}), the output voltage (V_{OUT}) gradually drops according to the input voltage (V_{IN}). If the input voltage drops more and becomes less than UVLO detector threshold (V_{UVLO1}), the under voltage lockout circuit (UVLO) operates, the IC internal reference voltage (V_{REF}) stops, switching transistors turn off and the output voltage drops according to the load and output capacitor C_{OUT} value. To restart the normal operation, the input voltage (V_{IN}) must be more than the UVLO released voltage (V_{UVLO2}).

The timing chart below describes the operation with varying the input voltage (V_{IN}).



*Actually, the waveform of Vout at UVLO working and releasing varies depending on the initial voltage of Cout and load current situation.

(3) Over Current Protection Circuit, Latch Type Protection Circuit

Over current protection circuit supervises the coil peak current (the current flowing Pch transistor) at each switching cycle, and if the current beyond the Lx current limit (ILXIim), Pch transistor is turned off. the Lx current limit of RP503x is Typ.800mA.

Further, if the over current status continues equal or longer than protection delay time, a built-in driver is latched in the OFF state and the operation of DC/DC converter stops.

*Lx current limit (ILXIIm) and protection delay time (tprot) is affected by self-heating and ambient environment. If the output is short and the input voltage (V_{IN}) is drastically dropped or becomes unstable, the protection operation and delay time may vary.



To release the condition of latch type protection, restart this IC by inputting "L" signal to CE pin, or restart this IC with power-on or make the supply voltage lower than UVLO detector threshold (VUVLO1) level.

The timing chart shown below describes the changing process of input voltage rising, stable operating, operating with large current, reset with CE pin, stable operating, input voltage falling, input voltage recovering, and stable operating.

If too large current flows through the circuit because of short or other reasons, after the delay time of latch type protection a built-in driver is latched in the OFF state and V_{LX} signal will be "L", then output will turn off. At the point (1), release the latch type protection is realized with CE reset as changed CE signal from "L" to "H".

At the point (2), release the latch type protection is realized with UVLO reset as make the supply voltage lower than UVLO detector threshold (VUVLO1) level.



TYPICAL CHARACTERISTICS*



2.54

2.53

2.52

2.51

2.50

2.49

2.48

2.47

2.46

0

100

200

Output Current IOUT (mA)

300

Output Voltage Vour (V)

VIN=3.6V

VIN=5.0V

400

500

5.5

I

5.0

5.5



2) Output Voltage vs. Input Voltage



RP503x25xA (PWM MODE)

IOUT=1mA IOUT=50mA IOUT=250mA iii 5.0 Input Voltage VIN (V)



1.1111 1 1 1 1

1 1 1 1

Output Current IOUT (mA)

RP503x15xA

10

1

0.1

50

40

30

20

10

0

0.01

1 1 1 1 1 1 1

1 1 1 1

100

1 1 1 1 1 1

1 1 1 1 1 1

1000

VIN=3.6V

VIN=5.0V

3) Output Voltage vs. Temperature





RP503x12xA

100























8) Oscillator Frequency vs. Temperature

9) Oscillator Frequency vs. Input Voltage

RP503x15xA



10) Soft-start Time vs. Temperature



Temperature Topt (°C)









12) CE Input Voltage vs. Temperature



RP503x15xA









15) Pch Tr. ON Resistance vs. Temperature





16) Turn on speed with CE pin (VIN=3.6V, Topt=25°C)



17) Load Transient Response (VIN=3.6V, Topt=25°C)



RP503x08xA



600

400

0 00 Output Current but (mA)



* RP503Z (WLCSP-6-P2) is the discontinued product. As of June in 2016. RP503x



RP503x12xA





RP503x12xA







RP503x18xA















RP503x25xA



RP503x25xA



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- 6. We are making our continuous effort to improve the quality and reliability of our products, but semiconductor products are likely to fail with certain probability. In order to prevent any injury to persons or damages to property resulting from such failure, customers should be careful enough to incorporate safety measures in their design, such as redundancy feature, fire containment feature and fail-safe feature. We do not assume any liability or responsibility for any loss or damage arising from misuse or inappropriate use of the products.
- 7. Anti-radiation design is not implemented in the products described in this document.
- 8. The X-ray exposure can influence functions and characteristics of the products. Confirm the product functions and characteristics in the evaluation stage.
- 9. WLCSP products should be used in light shielded environments. The light exposure can influence functions and characteristics of the products under operation or storage.
- 10. There can be variation in the marking when different AOI (Automated Optical Inspection) equipment is used. In the case of recognizing the marking characteristic with AOI, please contact our sales or our distributor before attempting to use AOI.
- 11. Please contact our sales representatives should you have any questions or comments concerning the products or the technical information.

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